

STRUCTURE	Silicon Monolithic Integrated Circuit
NAME OF PRODUCT	DC-AC Inverter Control IC
TYPE	BD9897FS

FUNCTION

36V High voltage process

• 1ch control with Full-Bridge

- Lamp current and voltage sense feed back control
- Sequencing easily achieved with Soft Start Control
- Short circuit protection with Timer Latch
- Under Voltage Lock Out
- Mode-selectable the operating or stand-by mode by stand-by pin
- Synchronous operating the other BD9897FS IC's
- BURST mode controlled by PWM and DC input
- Output liner Control by external DC voltage

OAbsolute Maximum Ratings (Ta =  $25^{\circ}$ C)

Parameter	Symbol	Limits	Unit
Supply Voltage	Vcc	36	۷
BST pin	BST	40	٧
SW pin	SW	36	٧
BST-SW voltage difference	BST-SW	7	٧
Operating Temperature Range	Topr	-40~+85	°C
Storage Temperature Range	Tstg	-55~+150	°C
Maximum Junction Temperature	Tjmax	+150	°C
Power Dissipation	Pd	950*	mW

\*Pd derate at 7.6mW/°C for temperature above Ta =  $25^{\circ}$ C (When mounted on a PCB 70.0mm × 70.0mm × 1.6mm) OOperating condition

Parameter	Symbol	Limits	Unit
Supply voltage	Vcc	7.5~30.0	V
BST voltage	BST	4. 0~36. 0	V
BST-SW voltage difference	BST-SW	4.0~6.5	V
CT oscillation frequency	fct	60~180	kHz
BCT oscillation frequency	fBCT	0.05~1.00	kHz

Status of this document

The Japanese version of this document is the official specification.

Please use the translation version of this document as a reference to expedite understanding of the official version.

If these are any uncertainty in translation version of this document, official version takes priority.



## O Electric Characteristics (Ta=25°C, VCC=24V)

Parameter			Limits			
	Symbol	MIN.	TYP.	MAX.	Unit	Conditions
((WHOLE DEVICE))						
Operating current	lcc1	-	7.2	13	mA	$CT_SYNC_IN = OPEN$
Stand-by current	lcc2	-	13.0	30.0	μA	
((STAND BY CONTROL))		•				•
Stand-by voltage H	VstH	2.0	-	VCC	٧	System ON
Stand-by voltage L	VstL	-0.3	-	0.8	V	System OFF
((UVLO BLOCK)))		1				-
Operating voltage (VCC)	VuvloH	5.7	6.0	6.3	٧	
Hesteresis width (VCC)	⊿VCC_Vuvlo	0.26	0.35	0. 43	٧	
Operating voltage (UVLO)	Vuvlo2	2. 179	2. 25	2. 321	۷	-
Hesteresis width (UVLO)	⊿Vuvlo	0. 074	0. 098	0. 122	۷	
((REG BLOCK))		5.00	5.00	5.00		1000 Z 011
REG output voltage	VREG	5. 68 20. 0	5.80 —	5.92	V	VCC>7. OV
REG source current ((OSC BLOCK))	IREG	20.0	-	—	mA	
Active edge setting current	lact	1.35/(RT*7)	1.5/(RT*6)	1.65/(RT*5)	A	
Negative edge setting current	Ineg	lact × 29	lact × 35	lact × 41	A	
OSC Max voltage	VOSCH	1.8	2.0	2.2	V	fCT=120kHz
OSC Min voltage	VOSCL	0, 35	0, 45	0, 60	V	fCT=120kHz
Soft start current	188	0.6	1.1	1.6	μA	=
SRT ON resistance	RSRT	-	1.1	200	Ω	
((BOSC BLOCK))						1
BOSC Max voltage	VBCTH	1, 94	2.00	2.06	V	fBCT=0. 3kHz
ő					-	-
BOSC Min voltage	VBCTL	0.40	0.50	0.60	V	fBCT=0. 3kHz
BOSC constant current	IBCT	1.35/BRT	1.5/RT	1.65/RT	A	VBCT=0. 2V
BOSC frequency	fBCT	291	300	309	Hz	(BRT=33k $\Omega$ BCT=0.048 $\mu$ F)
((FEED BACK BLOCK))						-
IS threshold voltage 1	VISO	1. 225	1.250	1.275	٧	
IS threshold voltage 2	VIS(2)	_	VREFIN	VIST	٧	VREF applying voltage
-	VVS	1. 220	1. 250	1. 280	v	
VS threshold voltage		-	-	0.9	-	
IS source current 1 IS source current 2	\$1	32	 50	68	μ Α μ Α	DUTY=2. 2V DUTY=0V IS=0. 5V
VS source current	1132	32	50	0.9	μ κ μ Α	DUTT-0V 13-0.5V
IS COMP detect voltage ①	VISCOMP(1)	0, 90	0, 94	0.98	V	VREFIN≧1.25V
IS COMP detect voltage 2	VISCOMP(2)	-	VREFIN×0.73	_	v	VREFIN<1.25V
VREF input voltage range	VREFIN	0.6	-	1.6	٧	No effect at VREF>1.25V
((DUTY BLOCK))						
High voltage	VDUTY-OUTH	2.8	3.1	3.4	٧	
Low voltage	VDUTY-OUTL	-	-	0.5	٧	
DUTY-OUT sink resistance	RDUTY-OUTSink	-	150	300	Ω	
DUTY-OUT source resistance	RDUTY-OUTSouce	-	250	500	Ω	
((OUTPUT BLOCK))	De Ludd N	0.75	1.5	2.0	Ω	
LN output sink resistance LN output source resistance	RsinkLN RsourceLN	0.75 2.5	1.5 5	3. 0 10	Ω	
HN output sink resistance	RsinkHN	2.5	2.5	5.0	Ω	VBST-VSW=5. OV
HN output sink resistance	RsourceLN	2.5	2.5	10	Ω	VBST-VSW=5. 0V
MAX DUTY	MAX DUTY	46.0	48.0	49.5	%	FOUT=60kHz
OFF period	TOFF	100	200	400	ns	
Drive output frequency	FOUT	58.5	60.0	61.5	kHz	(RT=4. 7kΩ CT=235pF)
((TIMER LATCH BLOCK))						
Timer Latch setting voltage	VCP	1.94	2.0	2.06	V	
Timer Latch setting current	ICP	0.40	0.55	0. 70	μA	
((COMP CLOCK))	MOCHEN	0.100	0.405	0.510	.,	1000 0 0V
COMP1 over voltage detect voltage	VCOMPH VCOMP2 H	2.460	2. 485	2.510	V V	VSS>2.2V
COMP2 over voltage detect voltage COMP2 under voltage detect voltage ①	VCOMP2_H VCOMP_L_1	2. 460 1. 225	2. 485 1. 25	2. 510 1. 275	V	VSS>2. 2V VSS>2. 2V
COMP2 under voltage detect voltage () COMP2 under voltage detect voltage (2)	VCOMP_L_1	0. 606	0. 625	0. 644	V	VSS<2. 2V VSS<2. 2V
((Synchronous Block))	100mr_L_2	0.000	0.020	0. 777	¥	100 12.21
High voltage	VCT_SYNCH	2.8	3.1	3.4	٧	
Low voltage	VCT_SYNCL	-		0.5	٧	1
CT_SYNC sink resistance	RCT_SYNC_SYNC	-	150	300	Ω	
CT_SYNC source resistance	RCT_SYNC_SOURCE	- 1	370	740	Ω	1
	VCT_SYNC_IN_H	2.0	-	3. 3	V	
High voltage input range		2.0	_	3. 5	v	

(This product is not designed to be radiation-resistant.)



## **OPackage Dimensions**



SSOP-A32 (Unit:mm)

## OBlock Diagram



PI No		FUNCTION				
1	PGND	Ground for FET drivers				
2	LN2	NMOS FET driver				
3	HN2	NMOS FET driver				
4	SW2	Lower rail voltage for $HN2$ output				
5	BST2	Boot-Strap input for HN2 output				
6	CT_SYNC_IN	CT synchronous signal input pin				
7	CT_SYNC_OUT	CT synchronous signal output pin				
8	SRT	External resistor from SRT to RT for adjusting the triangle oscillator				
9	RT	External resistor from SRT to RT for adjusting the triangle oscillator				
10	) CT	External capacitor from CT to GND for adjusting the triangle oscillator				
11	GND	GROUND				
12	2 BCT	External capacitor from BCT to GND for adjusting the BURST triangle oscillator				
13	BRT	External resistor from BRT to GND for adjusting the BURST triangle oscillator				
14	4 DUTY	Control PWM mode and BURST mode				
15	5 DUTY_OUT	BURST signal output pin				
16	6 STB	Stand-by switch				
17	7 CP	External capacitor from CP to GND for Timer Latch				
18	B FAIL	COMP2 under voltage protect clock output				
19	) VREF	Reference voltage input pin for Error amplifier				
20	VS VS	Error amplifier input				
21	IS	Error amplifier input				
22	2 FB	Error amplifier output				
23	3 SS	External capacitor from SS to GND for Soft Start Control				
24	COMP2	Under, over voltage detect pin				
25	5 COMP1	Over voltage detect pin				
26	6 VCC	Supply voltage input				
27	7 UVLO	External Under Voltage Lock Out				
28	B REG	Internal regulator output				
29	) BST1	Boot-Strap input for HN1 output				
30	) SW1	Lower rail voltage for HN1 output				
31	HN1	NMOS FET driver				
32	2 LN1	NMOS FET driver				

0.3MIN

0.15±0.1



ONOTE FOR USE

- When designing the external circuit, including adequate margins for variation between external devices and IC. Use adequate margins for steady state and transient characteristics.
- 2. The circuit functionality is guaranteed within of ambient temperature operation range as long as it is within recommended operating range. The standard electrical characteristic values cannot be guaranteed at other voltages in the operating ranges, however the variation will be small.
- 3. Mounting failures, such as misdirection or miscounts, may harm the device.
- 4. A strong electromagnetic field may cause the IC to malfunction.
- 5. The GND pin should be the location within  $\pm 0.3V$  compared with the PGND pin.
- 6. BD9897FS incorporate a built-in thermal shutdown circuit (TSD circuit). The thermal shutdown circuit (TSD circuit) is designed only to shut the IC off to prevent runaway thermal operation. It is not designed to protect the IC or guarantee its operation of the thermal shutdown circuit is assumed.
- 7. Absolute maximum ratings are those values that, if exceeded, may cause the life of a device to become significantly shortened. Moreover, the exact failure mode caused by short or open is not defined. Physical countermeasures, such as a fuse, need to be considered when using a device beyond its maximum ratings.
- 8. About the external FET, the parasitic Capacitor may cause the gate voltage to change, when the drain voltage is switching. Make sure to leave adequate margin for this IC variation.
- 9. On operating Slow Start Control (SS is less than 2.2V), It does not operate Timer Latch.
- 1 O. By STB voltage, BD9897FS are changed to 2 states. Therefore, do not input STB pin voltage between one state and the other state (0.8~2.0V).
- 1 1. The pin connected a connector need to connect to the resistor for electrical surge destruction. This IC is a monolithic IC which (as shown is Fig-1) has P<sup>+</sup> substrate and between the various pins. A P-N junction is formed from this P layer of each pin. For example, the relation between each potential is as follows,

O(When GND > PinB and GND > PinA, the P-N junction operates as a parasitic diode.)

O(When PinB > GND > PinA, the P-N junction operates as a parasitic transistor.)

Parasitic diodes can occur inevitably in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits as well as operation faults and physical damage. Accordingly you must not use methods by which parasitic diodes operate, such as applying a voltage that is lower than the GND (P substrate) voltage to an input pin.

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Fig-1 Simplified structure of a Bipolar IC

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